NSN 5961-01-125-2465

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View Online at https://aerobasegroup.com/nsn/5961-01-125-2465 **Inclosure Material:** Plastic and metal **Overall Length:** Between 0.570 inches and 0.620 inches **Overall Height:** Between 0.160 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.405 inches **End Application:** An/ugc-14 (v) **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage/static/emitter open and -100.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 26.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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